



DC Input 4-Pin High Power Photodarlington Optocoupler

Features

- High isolation 5000 VRMS
- CTR : Min 1000%
- High $B_{V_{CE0}} = 350V$
- RoHS Compliance
- REACH Compliance
- External Creepage $\geq 7.4mm$
- Distance Through Isolation $\geq 0.4mm$
- Spatial Distance $\geq 7.5mm$ (S/SL Type)
- Spatial Distance $\geq 8.0mm$ (M/SLM Type)
- Regulatory Approvals
 - UL - UL1577 (E364000)
 - VDE - EN60747-5-5(VDE0884-5)
 - CQC – GB4943.1, GB8898
 - IEC60065, IEC60950

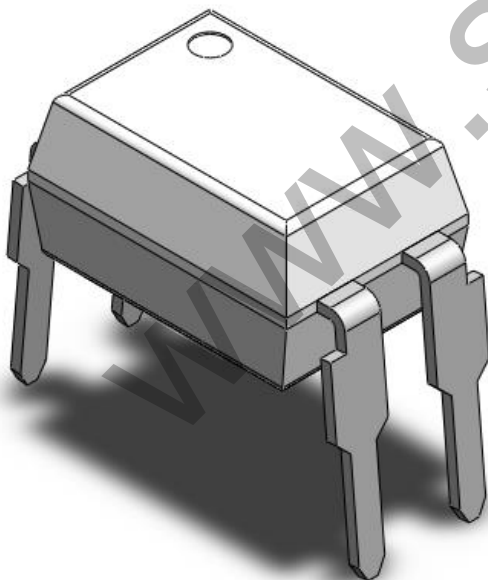
Description

The CT852 consists of a high power photodarlington transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead DIP package different lead forming options.

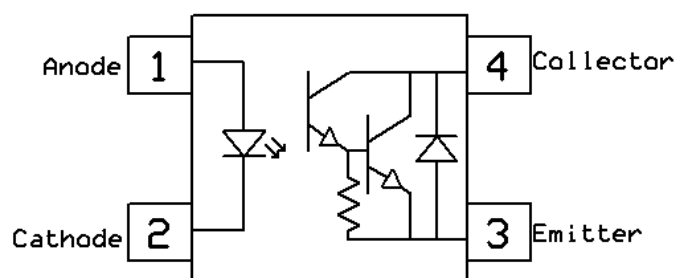
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Schematic



Note: Different lead forming options available. See package dimension.

**Absolute Maximum Rating at 25°C**

Symbol	Parameters	Ratings	Units	Notes
V _{ISO}	Isolation voltage	5000	V _{RMS}	
T _{OPR}	Operating temperature	-55 ~ +100	°C	
T _{STG}	Storage temperature	-55 ~ +150	°C	
T _{SOL}	Soldering temperature	260	°C	
Emitter				
I _F	Forward current	80	mA	
I _{F(TRANS)}	Peak transient current (≤1μs P.W,300pps)	1	A	
V _R	Reverse voltage	6	V	
P _D	Power dissipation	150	mW	
Detector				
P _D	Power dissipation	300	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	350	V	
B _{VECO}	Emitter-Collector Breakdown Voltage	0.1	V	
I _C	Collector Current	150	mA	



Electrical Characteristics

T_A = 25°C (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V _F	Forward voltage	I _F =10mA		1.24	1.4	V	
I _R	Reverse Current	V _R = 5V	-	-	5	μA	
C _{IN}	Input Capacitance	f= 1MHz	-	45	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
B _{VCEO}	Collector-Emitter Breakdown	I _C = 100μA	350	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _E = 100μA	0.1	-	-	V	
I _{CEO}	Collector-Emitter Dark Current	V _{CE} = 200V, I _F =0mA	-	-	100	nA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	I _F = 1mA, V _{CE} = 2V	1000		15000	%	
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	I _F = 20mA, I _C = 100mA	-	-	1.2	V	
R _{IO}	Isolation Resistance	V _{IO} = 500V _{DC}	5x10 ¹⁰			Ω	
C _{IO}	Isolation Capacitance	f= 1MHz		0.6		pF	

Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
t _r	Rise Time	I _C =2mA, V _{CE} = 2V, R _L = 100Ω	-	-	250	μs	
t _f	Fall Time		-	-	95		



Typical Characteristic Curves

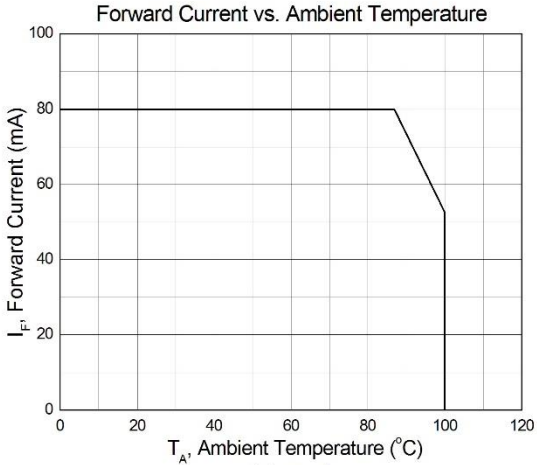


Figure 1

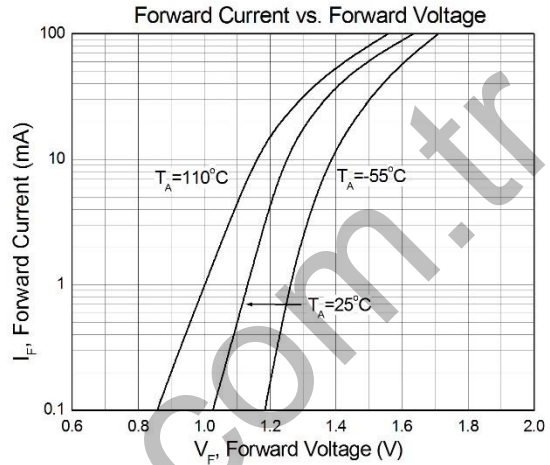


Figure 2

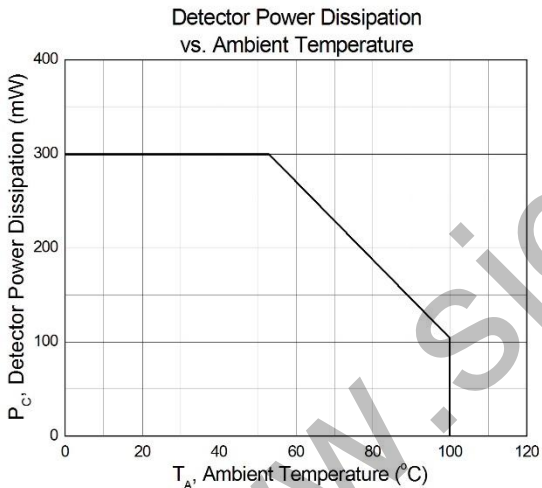


Figure 3

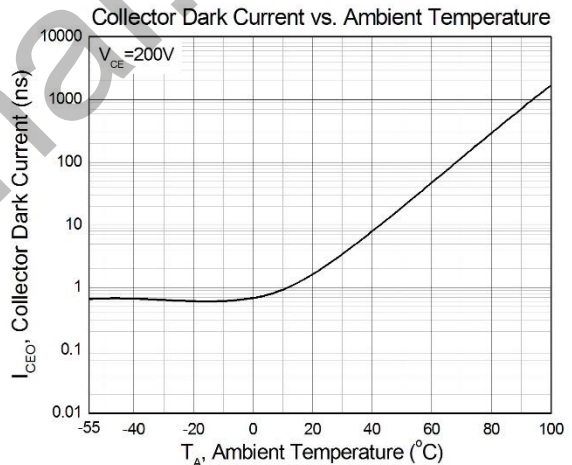


Figure 4

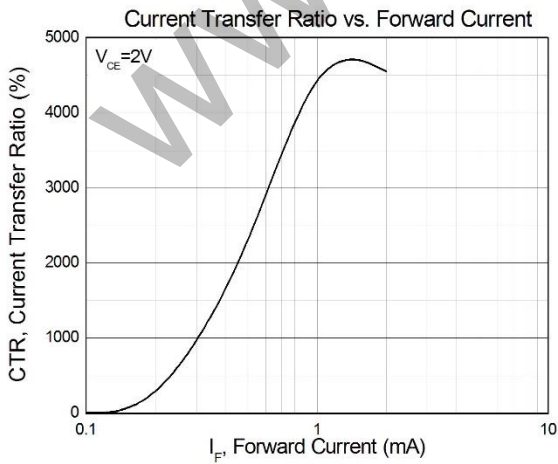


Figure 5

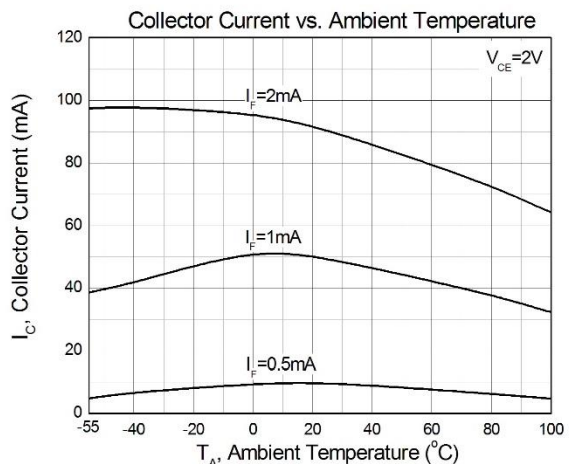


Figure 6



DC Input 4-Pin High Power Photodarlington Optocoupler

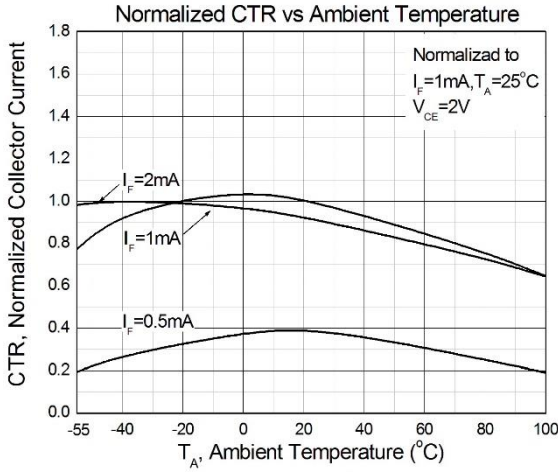


Figure 7

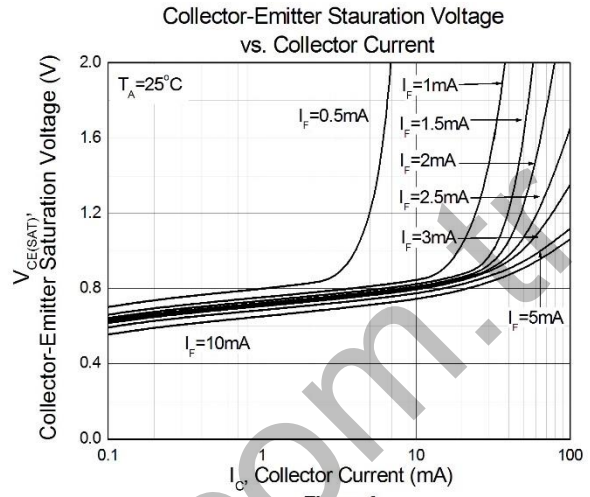


Figure 8

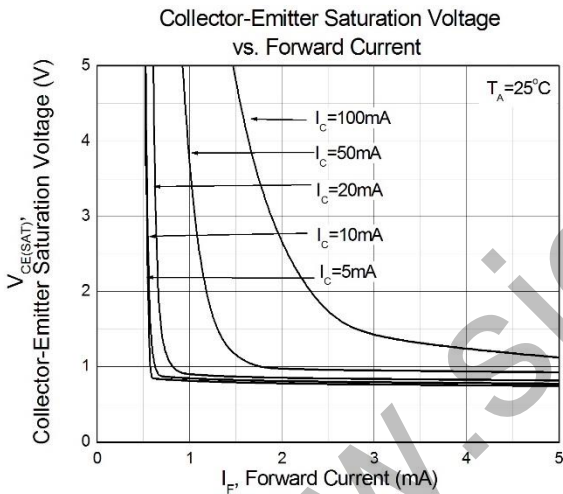


Figure 9

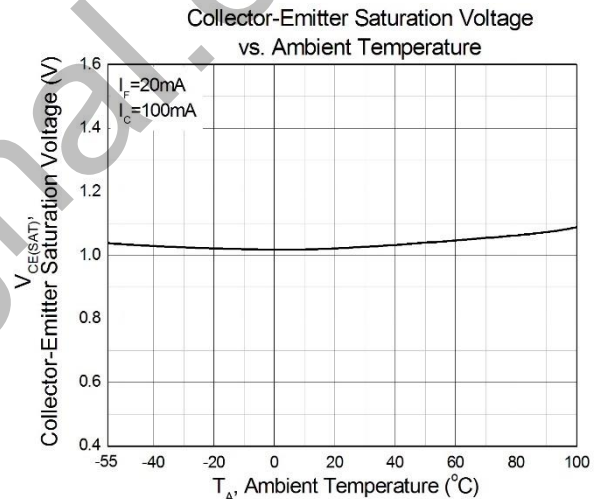


Figure 10

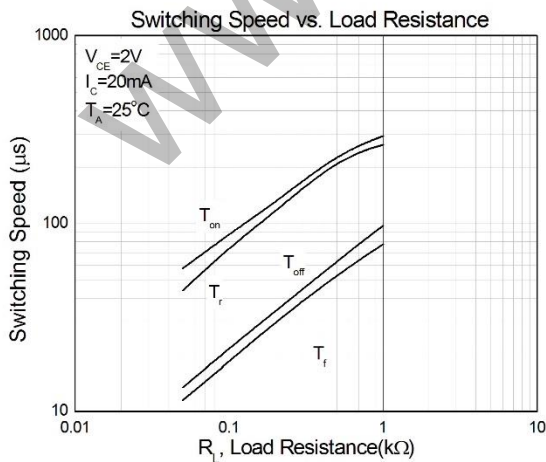


Figure 11

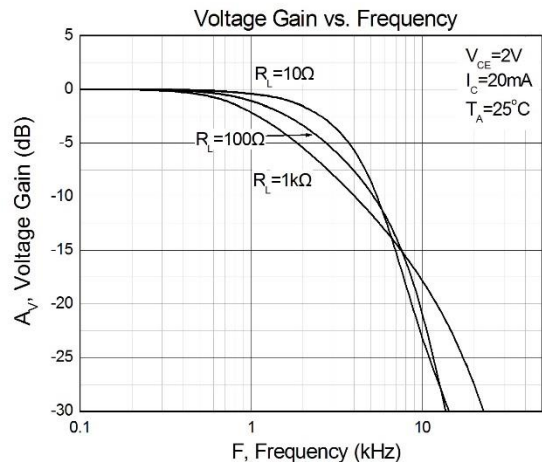
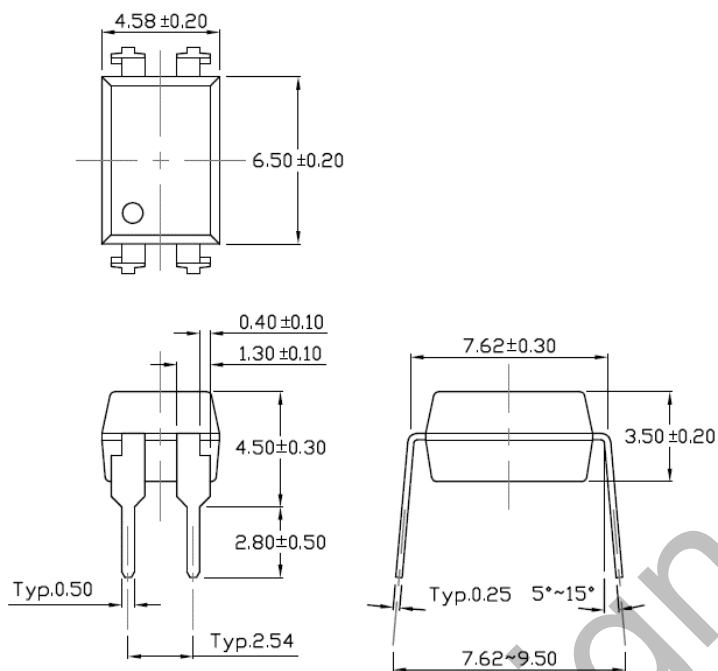


Figure 12

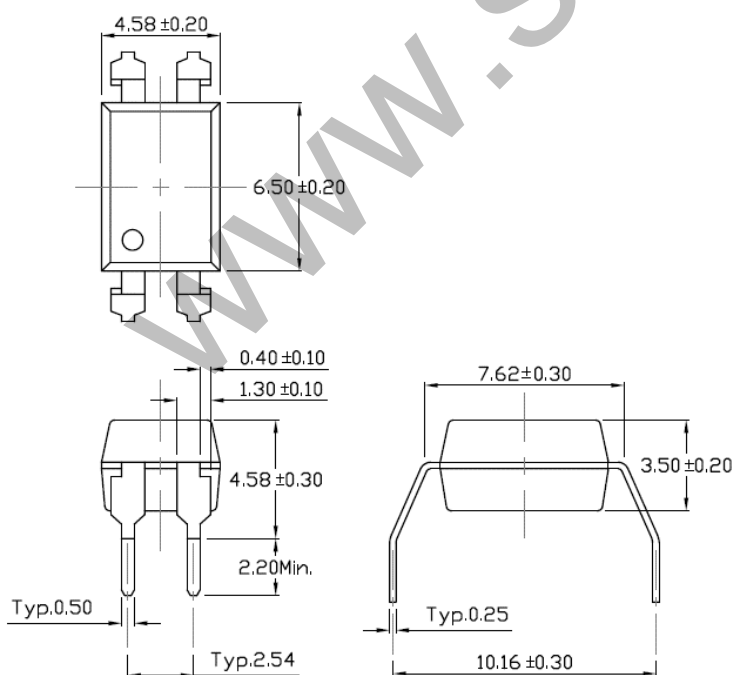


Package Dimension *Dimensions in mm unless otherwise stated*

Standard DIP – Through Hole

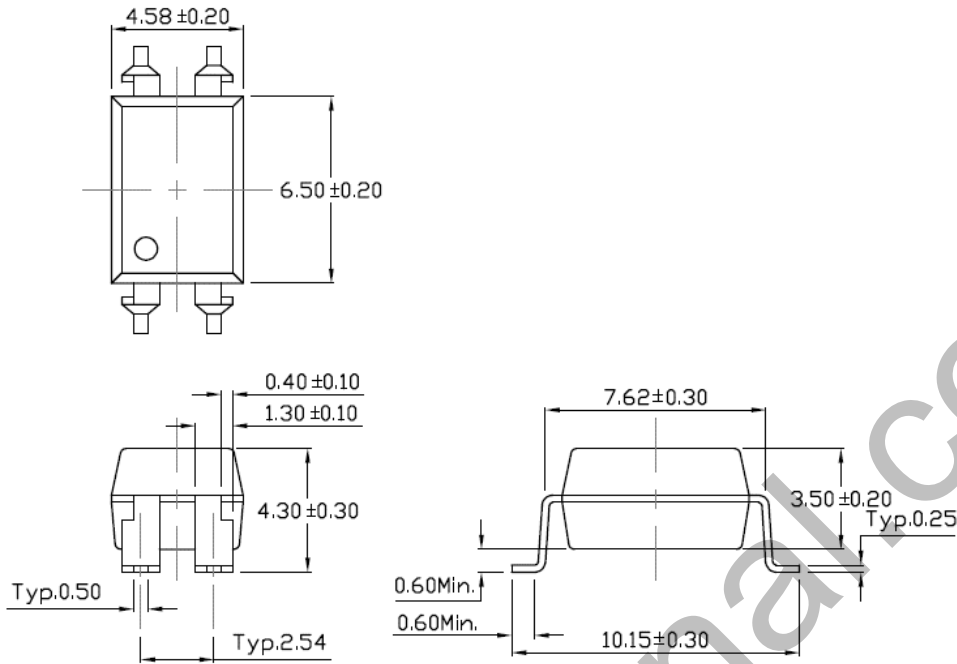


Gullwing (400mil) Lead Forming – Through Hole (M Type)

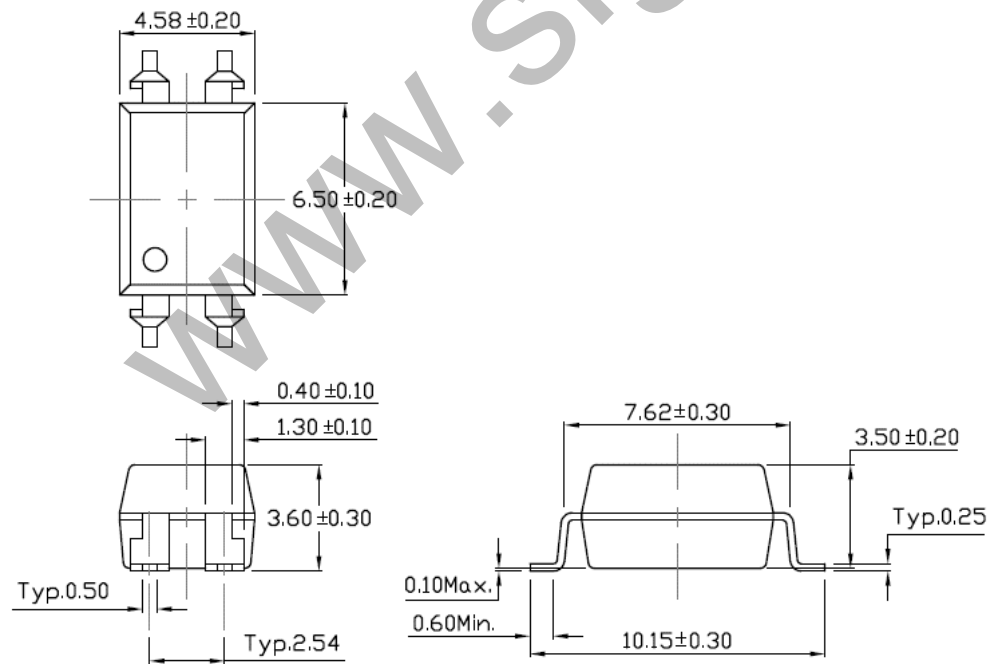




Surface Mount Lead Forming (S Type)

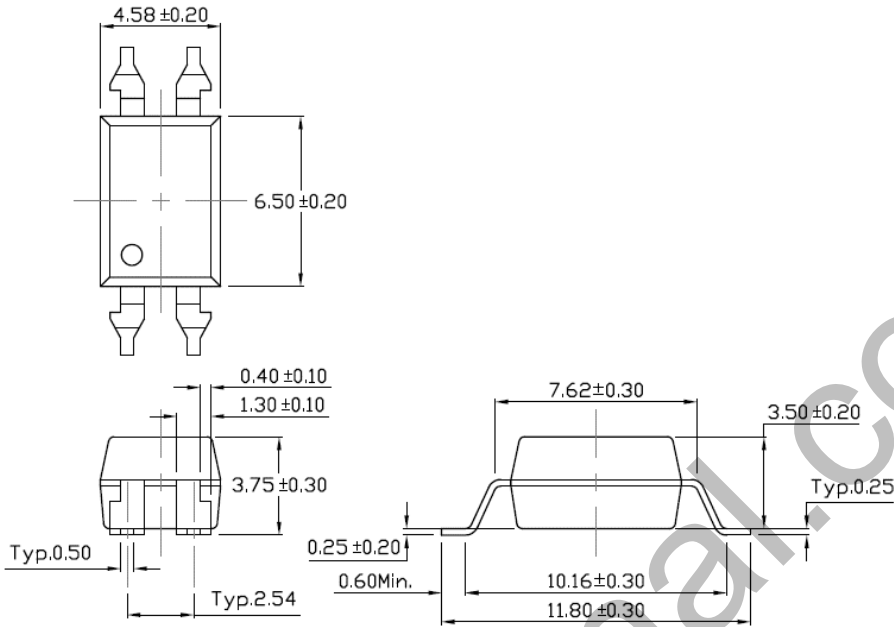


Surface Mount (Low Profile) Lead Forming (SL Type)



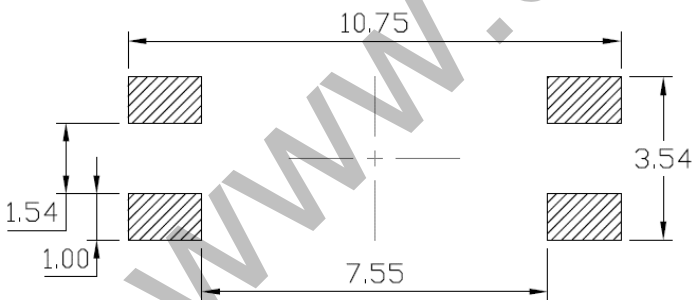


Surface Mount (Gullwing) Lead Forming (SLM Type)

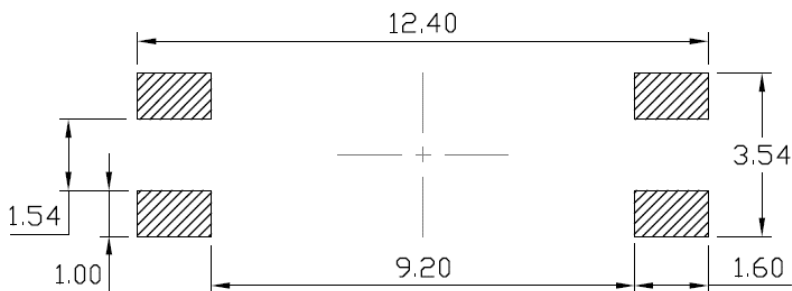


Recommended Solder Mask *Dimensions in mm unless otherwise stated*

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming





Marking Information

**Note:**

CT	: Denotes "CT Micro"
852	: Part Number
V	: VDE Option
Y	: Fiscal Year
WW	: Work Week
K	: Manufacturing Code

Ordering Information

CT852(V)(Y)(Z)-G

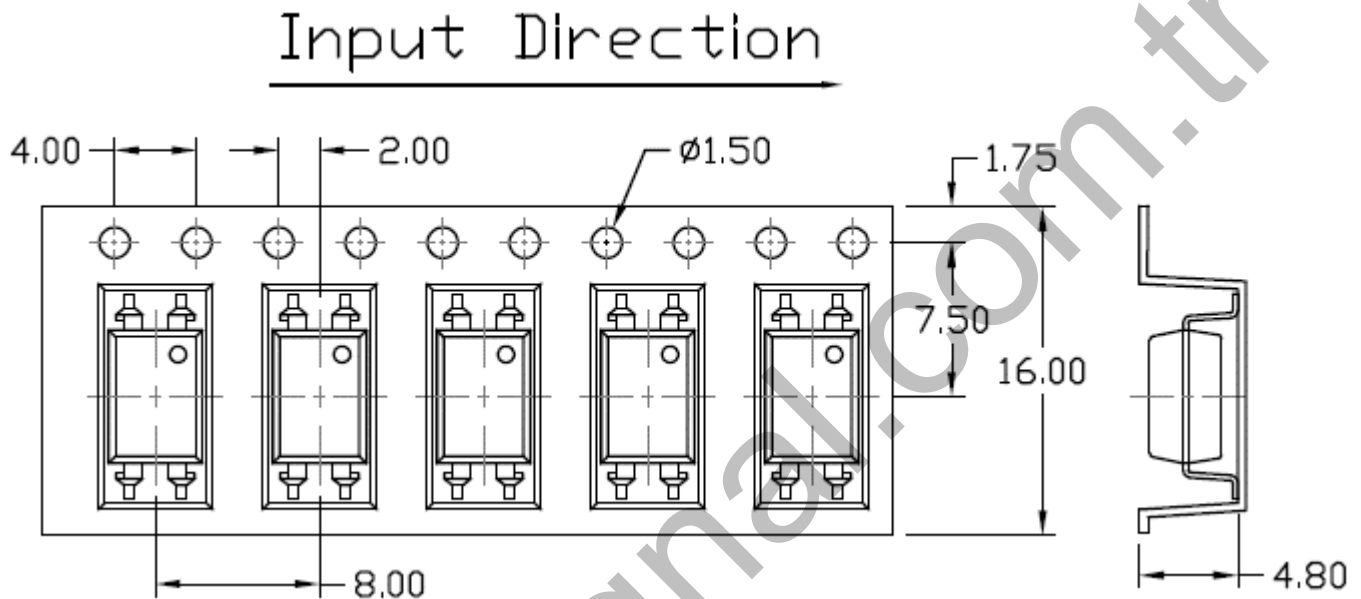
CT	= Denotes "CT Micro"
852	= Part Number
V	= VDE Option (V or None)
Y	= Lead form option (S, SL, M, SLM or none)
Z	= Tape and reel option (T1, T2, or none)
G	= Material option (G: Green, None: Non-green)

Option	Description	Quantity
None	Standard 4 Pin Dip	100 Units/Tube
M	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel

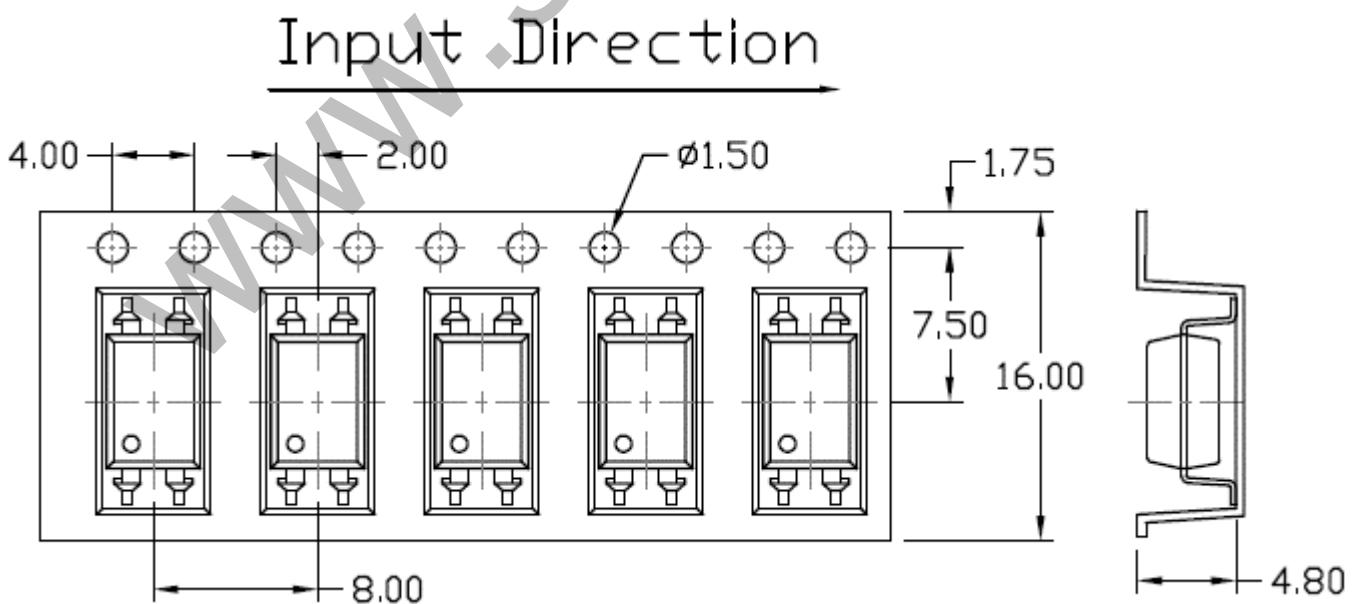


Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

Option S(T1) & SL(T1)



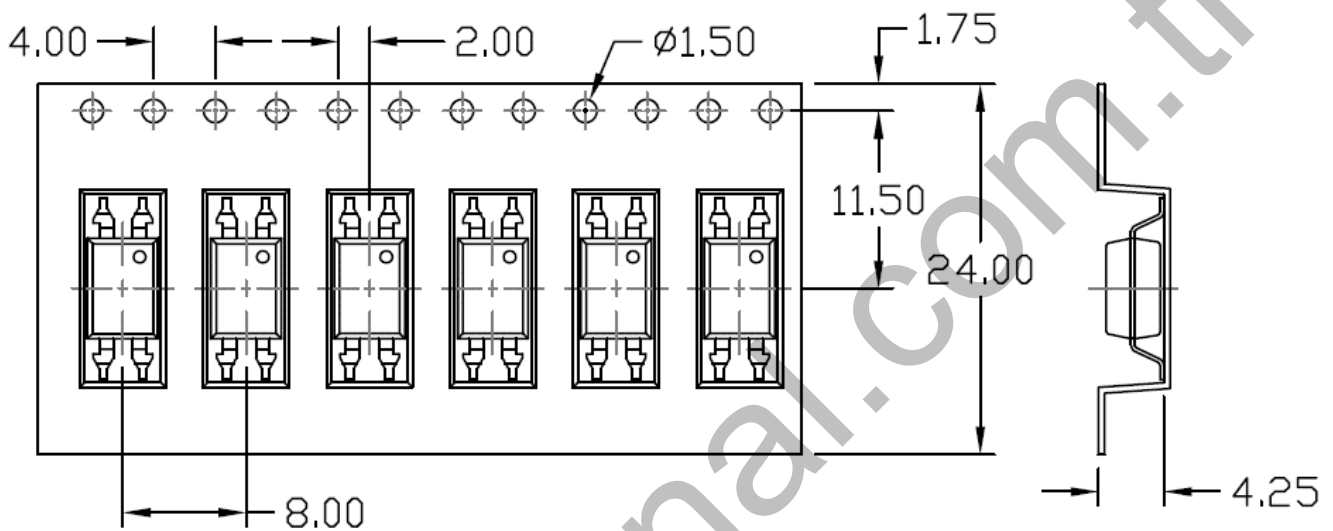
Option S(T2) & SL(T2)





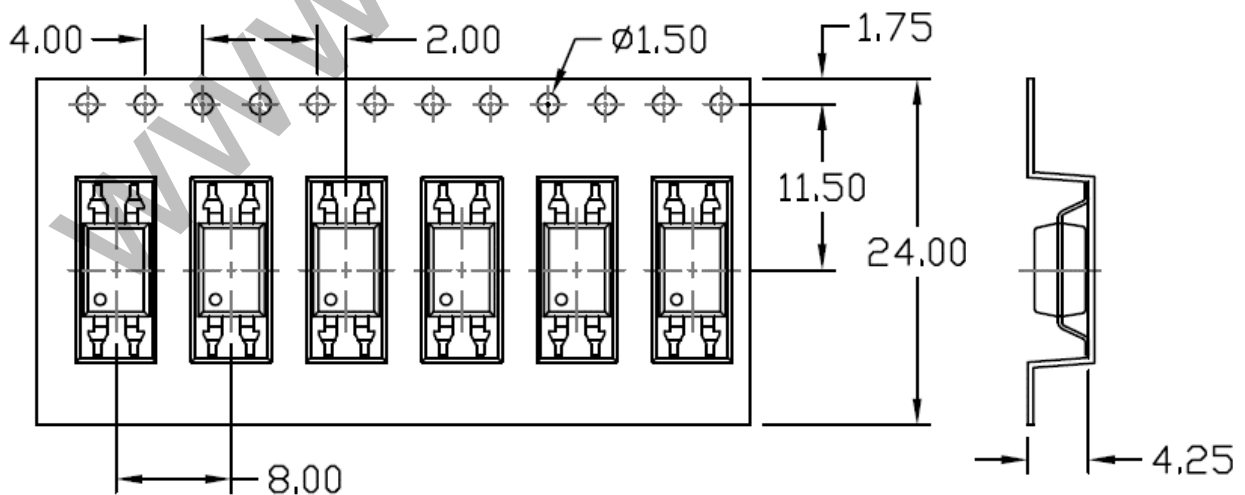
Option SLM(T1)

Input Direction



Option SLM(T2)

Input Direction





Wave soldering (follow the JEDEC standard JESD22-A111)

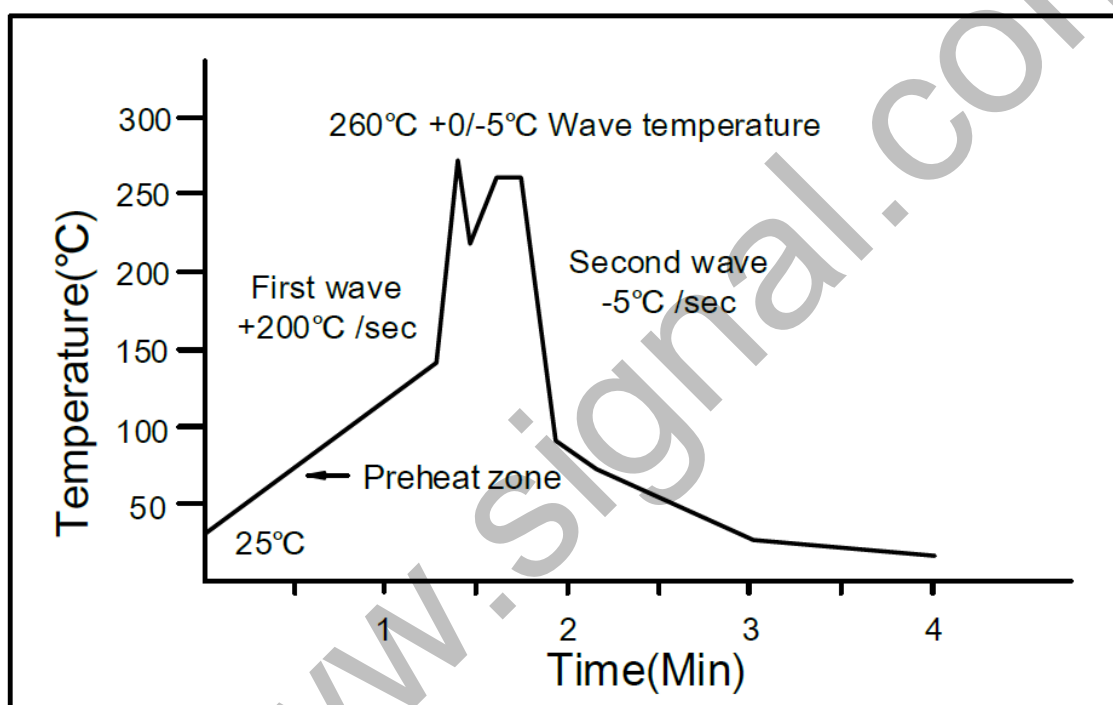
One time soldering is recommended within the condition of temperature.

Temperature: $260 \pm 5^\circ\text{C}$.

Time: 10 sec.

Preheat temperature: 25 to 140°C .

Preheat time: 30 to 80 sec.



Iron soldering (follow the standard MIL-STD 202G, Method 210F)

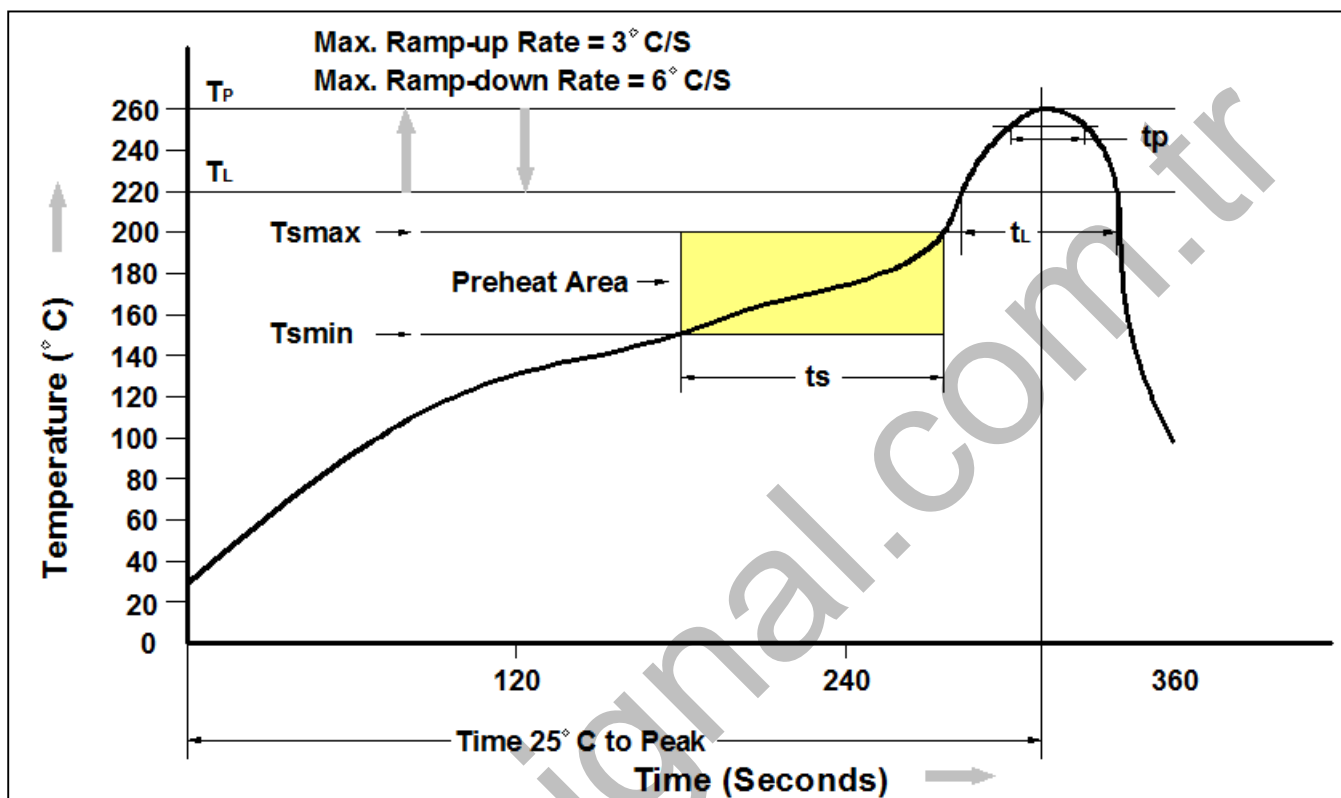
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: $350 \pm 10^\circ\text{C}$

Time: 5 sec max.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

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